11th European Symposium on Semiconductor Detectors

Wednesday, 10 June 2009

Coffee Break and Poster Session III - Molkehalle (10:40 - 11:40)

| [id] title | presenter | board |
|--|----------------------------|-------|
| [131] A planar position sensitive Si(Li)-detector for Compton polarimetry and Compton imaging | SPILLMANN, Uwe | |
| [130] Rietveld Refinement for the Crystal Structure of Ga2Se3 | SAVCHENKO, Konstantin | |
| [120] Surface Characterisation and Treatment Evaluation of Germanium Crystals | ENGERT, Tobias | |
| [121] Investigation of Lead Telluride Schottky Diode for Nuclear Radiation Detector Application | KIM, Geehyun | |
| [122] Planar and Semi-Planar Segmented HPGe Detectors for DESPEC Imaging Gamma-Array | KOJOUHAROV, Ivan | |
| [123] Encapsulated Germanium Detector with Electromechanical Cooling | KOJOUHAROV, Ivan | |
| [125] Fabrication of p-CdTe Schottky Detectors with Low Surface Leakage Current | MEETHALE, Palat Ushasree | |
| [126] The CdTe and CdZnTe single crystals growth essential X-ray imaging | PAVLYUK, Marina Dmitrievna | |
| [127] The Research of Polarization in CdTe P-I-N Detectors and Development of Detecting Units for High Resolution Spectroscopy | PETUKHOV, Yury | |
| [128] Duo-lateral 2D position-sensitive radiation (particle) detectors made of single crystal CVD diamond | POMORSKI, Michal | |
| [129] Planar Si(Li) detectors with a large active volume | SANDUKOVSKY, Viacheslav | |
| [114] Simulative analysis of Backscatter Factors(BSFs) for low energy X-ray | YUK, Sunwoo | |
| [88] Improved Coincidence Rejection For Silicon Drift Detectors | MOTT, Richard | |
| [111] Modelling the generation and dynamics of signal electrons in pixelized Si X-ray detectors | WEIDENSPOINTNER, Georg | |
| [110] Comparative study of PIN photodiodes for a low energy X-ray sensor between manufactured with three diverse wafer resistivity | PARK, Shin-Woong | |
| [113] NIR sensitivity enhancement by Laser Treatment for Si Detectors | YAMAMOTO, Koei | |
| [112] Nano5 - advancing radiation and particle transport schemes in Geant4 | WEIDENSPOINTNER, Georg | |
| [119] Epitaxial GaAs for X-ray detection | BOURGOIN, Jacques | |
| [118] Temperature dependence of AlGaAs soft X-ray detectors | BARNETT, Aidan Matthew | |
| [108] Study of frequency-dependent interstrip admittance in silicon microstrip detectors | GIACOMINI, Gabriele | |
| [109] Computer Simulation of Radiation Defect in Nanosandwich for Detection Applications | ILYIN, Arkady | |
| [102] Surface morphology and structure of porous silicon fabricated by vapor phase chemical etching | ADLIENE, Diana | |
| [103] Theoritical characterization of neutron semiconductor detector | BENZAID, Djelloul | |
| [100] Full differential front-end electronic for CMOS detectors. | SITEK, Piotr | |

| [101] A Fast Event-Preprocessor and Sequencer for the Simbol-X Low Energy Detector | TENZER, Chris |
|---|------------------------|
| [106] Enhanced radiation tolerance of Si detectors by addition of gold impurities: A simulation study | CEDOLA, Ariel Pablo |
| [107] The van Roosbroeck system, its mathematical properties, their use in simulation tools, and detector simulation examples | GÄRTNER, Klaus |
| [104] Impact of detector parameters on Light Charged Particle identification through pulse-shape analysis | CASTOLDI, Andrea |
| [105] Capacitance and electric field analytical calculations in strip semiconductor detectors | CATTANEO, Paolo Walter |
| [99] Noise analysis of the Charge Sensitive Amplifier(CSA) for Photodetection | PARK, Shin-Woong |
| [98] Characterisation of an adaptive gain silicon microstrip readout chip. | MOZZANICA, Aldo |
| [91] The readout electronics for eROSITA pnCCD testing | ELBS, Johannes |
| [93] Comparison of events reconstruction techniques in imaging detectors based on signal sharing | FIORINI, Carlo |
| [92] Readout ASICs for Silicon Drift Detectors | FIORINI, Carlo |
| [95] Proposal of a fast readout logic for large pixel devices | GABRIELLI, Alessandro |
| [94] Current Readout strategy for XFEL DEPFET detector | FIORINI, Carlo |
| [97] Introducing 65 nm CMOS technology in low-noise read-out of semiconductor detectors | MANGHISONI, Massimo |
| [96] DAQ system for pixel detectors R&D | GIUBILATO, Piero |
| [117] Study of p-type fast neutron irradiated silicon diodes | LYTOVCHENKO, Oleksiy |
| [116] Performance of n^+-in-n Pixel Sensors at Highest Fluences | MUENSTERMANN, Daniel |